NSN 5961-01-112-0928

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-112-0928 **Inclosure Material:** Ceramic **Overall Length:** Between 0.095 inches and 0.105 inches **Overall Diameter:** Between 0.019 inches and 0.021 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 breakdown voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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